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## **CONTRIBUTIONS TO GROUP IV ORGANOMETALLIC CHEMISTRY**

# VII \*. THE EFFECT OF ELECTRONEGATIVITY ON SUBSTITUENT SHIFTS IN SILICON-29 NMR

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### Summary

Silicon-29 NMR shifts for silanes of the type  $Me_{2-n}Ph_nSiX_2$  (X = H, Me, Ph, F, Cl, NR<sub>2</sub> and OR) indicate that the shifts on replacement of a methyl by a phenyl group are largely determined by the electronegativity and donor ability of X.

A study of the silicon-29 NMR shift values for the series  $Me_{4.n}SiPh_n$  indicated a fairly constant shift of about -4 ppm on replacement of a Me by a Ph group [2,3,4] although it was subsequently suggested that in general substituent parameters can only be used with caution [5,6,7].

In the course of our detailed investigation of 1,3-dioxa- and 1,3-diaza-2-silacycloalkanes and their precursors [8,9] we have obtained silicon-29 NMR shifts for a range of dialkoxy- and bis(dialkylamino)-silanes. The results show that the methyl  $\rightarrow$  phenyl substituent shift is relatively constant for the same class of compound and a comparison with literature shift values for other compounds of the type Me<sub>2-n</sub>Ph<sub>n</sub>SiX<sub>2</sub> suggests that the magnitude of the effect is dependent on the electronegativity of X.

### **Results and discussion**

Silicon-29 NMR shifts and methyl  $\rightarrow$  phenyl substituent shifts ( $\Delta\delta$ ) are given in Table 1, literature values being a mean of shifts taken from a review by Marsmann [6].

The general dependence of  $\Delta\delta$  on the Pauling electronegativity of atoms X directly bonded to silicon is shown in Fig. 1, with OMe and NMe<sub>2</sub> representative of alkoxy and dialkylamino groups. The points appear to produce two sets of lines, of marginally different gradient for the first and second substituents, with the electro-

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<sup>\*</sup> For part VI see Ref. 1.

#### TABLE 1

x	n			Δδ	
	0	1	2	$Me_2 \rightarrow PhMe$	$MePh \rightarrow Ph_2$
H "	- 39.60	- 36.80	- 33.79	+ 2.8	+ 3.01
Me "	0	- 4.78	- 8.62	4.78	- 3.84
Ph "	- 8.62	-12.05	- 13.98	- 3.43	- 1.93
Cl a	+ 31.93	+17.90	+ 6.25	-14.03	-11.65
NMe <sub>2</sub>	-1.07	9.06	-17.04	- 7.99	- 7.98
NEt <sub>2</sub>	- 5.52	-11 32	_	- 5.80	-
OMe	-2.28 <sup>a</sup>	- 14.89	- 29.11	12.61	-14.22
OEt	- 6.25 <i>"</i>	-18.43	- 32.36	-12.18	- 13.93
OPr'	- 8.29	- 21.96	- 35.78	-13.67	-13.82
OPh	-6.10(2)	- 21.19	- 37.37	- 15.09	- 16.18
F	+ 4.45	- 12.40	- 29.8	- 16.85	-17.4

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" Ref. 5, mean values.

negative atoms N, O and F common to one set. Since these are the atoms which might be expected to back donate most strongly it is noteworthy that the  $\Delta\delta$  values are less than would be obtained by extrapolation of the lines containing H. C and Cl.

One interpretation of these results is that the increased shielding at silicon which results from phenyl substitution is due to  $(p \rightarrow d)\pi$  bonding from the phenyl group and that this would be enhanced by the presence of electronegative substituents X (Ph $\neg$ Si  $\rightarrow$  X). If however X were itself capable of  $(p \rightarrow d)$  back donation this would partially offset the  $\pi$ -bonding between phenyl and silicon which would tend to



Fig. 1.  $\Delta(Me \rightarrow Ph) \,\delta(^{29}Si)$  for compounds containing the  $X_2Si \subset Mee_1 \rightarrow MePh, \Delta MePh \rightarrow Ph_2$ . \* Electronegativity of atom in X bonded directly to silicon (after Pauling [11]).

reduce the increase in shielding ( $Ph \stackrel{-}{\rightarrow} Si \stackrel{-}{\rightarrow} X$ ). Also compatible with this explanation are the somewhat higher  $\Delta\delta$  values when X is a phenoxy, rather than an alkoxy, group since some delocalisation of oxygen electrons into the oxygen-phenyl bond and away from silicon would be expected ( $Ph \stackrel{-}{\rightarrow} Si \rightarrow O\stackrel{-}{\rightarrow} Ph$ ).

Substituent effects do not appear to have been connected with electronegativity in precisely this way before, although the linear relationship between absolute shift values and the electronegativity of X in compounds of the type Me<sub>3</sub>SiX has been established [2]. The ligands N, O and F were found to be exceptional, and were observed to produce less deshielding of the silicon atom than might be expected, and the effect was attributed to  $(p \rightarrow d)\pi$  bonding. It is of interest to note that, as reported by Wells [10], the  $\pi$  bonded phenyl groups and vinyl groups are found in the same category as N, O and F.

We associate the lower  $\Delta\delta$  value, for Me<sub>2</sub>Si(NEt<sub>2</sub>)<sub>2</sub> (-5.80 ppm) as compared to Me<sub>2</sub>Si(NMe<sub>2</sub>)<sub>2</sub> - 7.99 ppm) with steric crowding in MePhSi(NEt<sub>2</sub>)<sub>2</sub>, this view being supported by the fact that we were unable to prepare Ph<sub>2</sub>Si(NEt<sub>2</sub>)<sub>2</sub> from the interaction of dichlorodiphenylsilane and diethylamine.

### Experimental

Dialkoxy- and bis(dialkylamino)-silanes were prepared from the appropriate dichlorosilanes by established methods.

Silicon-29 NMR spectra were recorded on a JEOL-PS-100 NMR spectrometer in the Fourier transform mode using solutions of the sample in either  $CDCl_3$  or  $CCl_4$  with internal TMS as the standard. A trace of chromium acetylacetonate was used as a relaxation agent for some of the spectra.

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